



QUADRUPLE 2-INPUT NAND GATES WITH SCHMITT TRIGGER INPUTS

Description

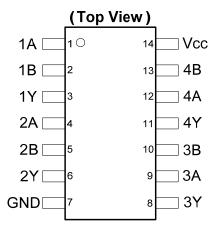
The 74LV132A provides provides four independent 2-input NAND gates with standard push-pull outputs. Each input is a Schmitt Trigger device with a significant amount of hysteresis suiting the device for noisy environments. The device is designed for operation with a power supply range of 2.0V to 5.5V.

The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down.

The gates perform the Boolean function:

$$Y = \overline{A \bullet B}$$
 or $Y = \overline{A} + \overline{B}$

Pin Assignments



SO-14 / TSSOP-14

Features

- Wide Supply Voltage Range from 2.0V to 5.5V
- Sinks or sources 12mA at V_{CC} = 4.5V
- CMOS low power consumption
- I_{OFF} Supports Partial -Power Down Operation
- Inputs or Outputs accept up to 5.5V
- Inputs can be driven by 3.3V or 5V allowing for voltage translation applications.
- Schmitt Trigger Action at All Inputs
- ESD Protection Tested per JESD 22
 - Exceeds 200-V Machine Model (A115)
 - Exceeds 2000-V Human Body Model (A114)
 - Exceeds 1000-V Charged Device Model (C101)
- Latch-Up Exceeds 100mA per JESD 78, Class I
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Applications

- General Purpose Logic
- Power Down Signal Isolation
- Wide array of products such as:
 - PCs, networking, notebooks, ultrabooks, netbooks
 - Computer peripherals, hard drives, CD/DVD ROM
 - TV, DVD, DVR, set top box

Notes:

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- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

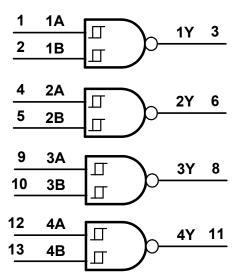
Click for Ordering Information



Pin Descriptions

Pin Number	Pin Name	Description
1	1A	Data Input
2	1B	Data Input
3	1Y	Data Output
4	2A	Data Input
5	2B	Data Input
6	2Y	Data Output
7	GND	Ground
8	3Y	Data Output
9	3A	Data Input
10	3B	Data Input
11	4Y	Data Output
12	4A	Data Input
13	4B	Data Input
14	Vcc	Supply Voltage

Logic Diagram



Function Table

Inp	Output	
Α	В	Y
Н	Н	L
L	X	Н
X	L	Н

Absolute Maximum Ratings (Note 4)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	٧
V _{CC}	Supply Voltage Range	-0.5 to 7.0	V
VI	Input Voltage Range note 4	-0.5 to 7.0	V
lık	Input Clamp Current V _I < 0V	-20	mA
I _{OK}	Output Clamp Current V _O < -0V	-50	mA
lo	Continuous Output Current - 0.5V < V _O V _{CC} + 0.5V	+/- 25	mA
Icc	Continuous Current Through Vcc	50	mA
I _{GND}	Continuous Current Through GND	-50	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
P _{TOT}	Total Power Dissipation	500	mW

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

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Recommended Operating Conditions (Note 5)

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	Supply Voltage	-	2.0	5.5	V
VI	Input Voltage	-	0	5.5	V
Vo	Output Voltage	-	0	V _{CC}	V
	High-Level Output Current	2.0V	_	-50	mA
l ,		2.3V to 2.7V	_	-2	μΑ
Іон		3.0V to 3.6V	_	-6	mA
		4.5V to 5.5V	_	-12	mA
		2.0V	_	50	μΑ
l .	Low Lovel Output Current	2.3V to 2.7V	_	2	mA
l _{OL}	Low-Level Output Current	3.0V to 3.6V	_	6	mA
		4.5V to 5.5V	_	12	mA
T _A	Operating Free-Air Temperature	-	-40	+125	°C

Note: 5. Unused inputs should be held at Vcc or Ground.

Electrical Characteristics

				T _A = -40	to +85°C	T _A = -40 1	to +125°C	
Symbol	Parameter	Test Conditions	Vcc	Min	Max	Min	Max	Unit
		-	2.5 V	1	1.75	1	1.75	
V_{T+}	Positive Going Threshold	_	3.3 V	1.31	2.31	1.31	2.31	V
		-	5.0 V	1.95	3.5	1.95	3.5	
		-	2.5 V	0.75	1.5	0.75	1.5	
V_{T-}	Negative Going Threshold	_	3.3 V	0.99	2.07	0.99	2.07	_
		-	5.0 V	1.5	3.05	1.5	3.05	
		-	2.5 V	0.25	1	0.25	1	
V _H	Hysteresis (V _{T+-} V _{T-)}	-	3.3 V	0.33	1.32	0.33	1.32	V
	(*11-*1-)	-	5.0 V	0.5	2	0.5	2	
		I _{OH} = -50μA	2.0V to 5.5V	V _{CC} -0.1	_	V _{CC} -0.1	_	
	High-Level	I _{OH} = -2mA	2.3V	2.0	_	2.0	-] ,,
V _{OH}	Output Voltage	I _{OH} = -6mA	3.0V	2.48	_	2.48	_	V
		I _{OH} = -12mA	4.5V	3.8	_	3.8	_	
		I _{OL} = 50μA	2.0V to 5.5V	_	0.1	_	0.1	
.,	Low-Level	I _{OL} = 2mA	2.3V	-	0.4	_	0.4	V
V_{OL}	Output Voltage	I _{OL} = 6mA	3.0V	-	0.44	_	0.44] v
		I _{OL} = 12mA	4.5V	_	0.55	_	0.55	
l _{OFF}	Power Down Leakage Current	V_{I} or $V_{O} = 0$ to 5.5V	0V	-	5	-	5	μΑ
II	Input Current	V _I =GND or 5.5V	0 to 5.5V	_	±1	_	±1	μΑ
Icc	Supply Current	$V_I = GND \text{ or } V_{CC}$ $I_O=0$	5.5V	_	20	_	20	μΑ



Switching Characteristics

Symbol	nbol Parameter Test		Test		T _A = +25°C		-40 to +85°C		-40 to +125°C		Unit
Syllibol	Parameter	Conditions	V _{CC}	Min	Тур.	Max	Min	Max	Min	Max	Onit
		Figure 1	2.5V ± 0.2V	-	7.9	16.5	1	18.5	1	18.5	
		Figure 1 C _L =15pF	3.3V ± 0.3V	-	5.6	11.9	1	14	1	14	ns
	Propagation	CL=15pF	5.0V ± 0.5V	-	3.9	7.7	1	9	1	9	
t _{PD}	Delay A _N to Y _N		2.5V ± 0.2V	_	10.8	20.2	1	23	1	23	
	Figure 1 C _L =50 p		3.3V ± 0.3V	_	7.6	15.4	1	17.5	1	17.5	ns
		OL-30 pi	5.0V ± 0.5V	_	5.3	9.7	1	11	1	11	1

Operating Characteristics T_A = +25°C

Parameter		Test Conditions	V _{CC}	ТҮР	Unit
	Power Dissipation	F= 10 MHz	3.3V	7.5	nE
C _{pd}	Capacitance per Gate	C _L =50pF	5.0V	11.2	pF

Noise Characteristics

 $\overline{V_{CC}} = 3V, C_L = 50pF, T_A = +25^{\circ}C$

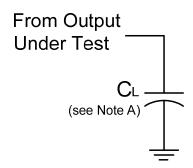
Symbol	Parameter	Min	Тур.	Max	Unit
V _{OL(p)}	Quiet output, maximum dynamic V _{OL}	_	0.2	0.8	V
$V_{OL(V)}$	Quiet output, minimum dynamic V _{OL}	_	-0.1	-0.8	V
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}	_	3.1	_	V
$V_{IH(D)}$	High Level dynamic input voltage	2.31	-	-	V
$V_{IL(D)}$	Low Level dynamic input voltage	-	-	0.99	V

Package Characteristics

Symbol	Parameter	Test Conditions	Vcc	Min	Тур.	Max	Unit
Ci	Input Capacitance	$V_i = V_{CC} - \text{ or GND}$	2.0 to 5.5V	-	3.3	10	pF



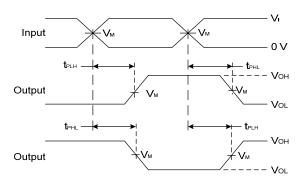
Parameter Measurement Information



V _{cc}	Inp	outs	V _M	CL
	VI	t _r / t _f		
2.0V to 5.5V	V _{CC}	<3ns	V _{CC} / 2	15pF or 50pF



Voltage Waveform Pulse Duration



Voltage Waveform
Propagation Delay Times
Inverting and Non Inverting Outputs

Notes: A. Includes test lead and test apparatus capacitance.

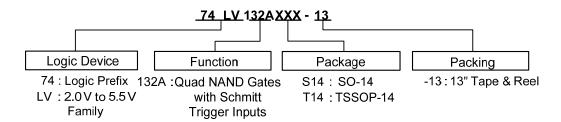
- B. All pulses are supplied at pulse repetition rate ≤ 10MHz
- C. Inputs are measured separately one transition per measurement
- D. t_{PLH} and t_{PHL} are the same as t_{PD}

Figure 1. Load Circuit and Voltage Waveforms

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Ordering Information

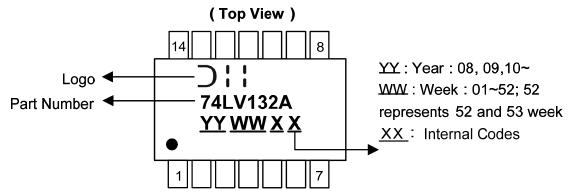


Device	Backago Codo	Packaging	13" Tape	and Reel
Device	Package Code	(Note 6)	Quantity	Part Number Suffix
74LV132AS14-13	S14	SO-14	2500/Tape & Reel	-13
74LV132AT14-13	T14	TSSOP-14	2500/Tape & Reel	-13

Note: 6. The taping orientation and tape details can be found at http://www.diodes.com/datasheets/ap02007.pdf

Marking Information

(1) SO14, TSSOP14

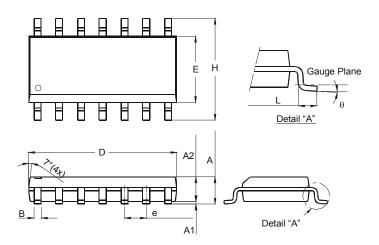


Part Number	Package
74LV132AS14	SO-14
74LV132AT14	TSSOP-14



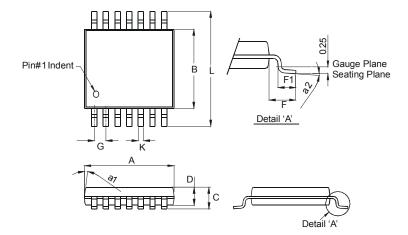
Package Outline Dimensions (All Dimensions in mm)

Package Type: SO-14



SO-14		
Dim	Min	Max
Α	1.47	1.73
A1	0.10	0.25
A2	1.45 Typ	
В	0.33	0.51
D	8.53	8.74
Е	3.80	3.99
е	1.27 Typ	
Н	5.80	6.20
L	0.38	1.27
θ	0°	8°
All Dimensions in mm		

Package Type: TSSOP-14

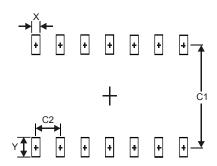


TSSOP-14		
Dim	Min	Max
a1	7° (4X)	
a2	0°	8°
Α	4.9	5.10
В	4.30	4.50
С	_	1.2
D	8.0	1.05
F	1.00 Typ	
F1	0.45	0.75
G	0.65 Typ	
K	0.19	0.30
L	6.40 Typ	
All Dimensions in mm		



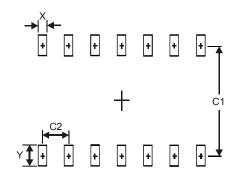
Suggested Pad Layout

Package Type: SO-14



Dimensions	Value (in mm)
Х	0.60
Y	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimensions	Value (in mm)
X	0.45
Υ	1.45
C1	5.9
C2	0.65

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